

General Description

This product family offers state of the art performance. It is designed for high frequency applications where high efficiency and high reliability are required.

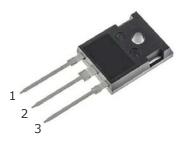
Features

- Low conduction loss due to low VF
- Extremely low switching loss by tiny Qc
- Highly rugged due to better surge current
- Industrial standard quality and reliability

Applications

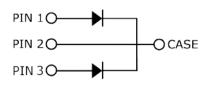
- UPS
- Power Inverter
- High performance SMPS
- Power factor correction

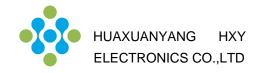
Ordering Part Number	Package	Qty(PCS)	
HSCS220AE2HR	TO-247	30	



TO-247

Package



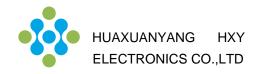


Maximum Ratings (at Tj = 25 °C, unless otherwise specified)

Parameter	Symbol	Value	Unit	
Repetitive Peak Reverse Voltage	Vrrm	650	V	
Surge Peak Reverse Voltage	Vrsm	650	V	
DC Peak Reverse Voltage	VR	650	V	
Continuous Forward Current $Tc = 25^{\circ}C$ $Tc = 135^{\circ}C$ $Tc = 160^{\circ}C$	lF	38/76 19/38 10/20	A	
Repetitive Peak Forward Surge Current $Tc = 25^{\circ}C, t_{p}=10ms, Half Sine Pulse$ $Tc = 110^{\circ}C, t_{p}=10ms, Half Sine Pulse$	IFRM	45 27	A	
Non-Repetitive Forward Surge Current $Tc = 25^{\circ}C, t_{p}=10ms, Half Sine Pulse$ $Tc = 110^{\circ}C, t_{p}=10ms, Half Sine Pulse$	IFSM	80 70	A	
i ² dt value Tc = 25°C,t _P =10ms,Half Sine Pulse Tc = 110°C,t _P =10ms,Half Sine Pulse	∫ i²dt	31.7 24.3	A²s	
Power dissipation Tc = 25°C Tc = 110°C	Ptot	116/232 50/100	W	
Operating junction Range	Tj	-55 to +175	°C	
Storage temperature Range	Tstg	-55 to +150	°C	

Thermal Resistance

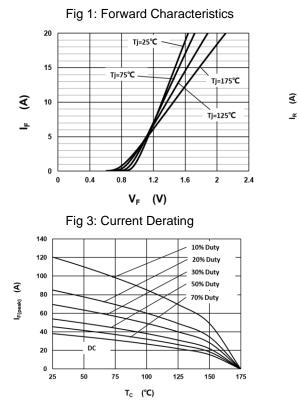
Parameter	Symbol	Value	Unit
Thermal resistance, junction – case.	RthJC	1.29/0.65	°C/W

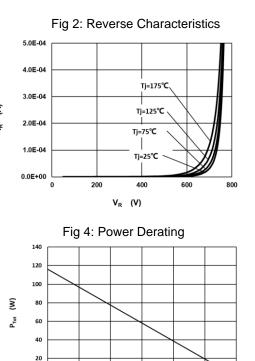


Deremeter	Value Value			L Incit	Test Condition		
Parameter	Symbol	min.	typ.	max.	Unit	Test Condition	
					V	I⊧=10A	
Forward Voltage	VF	-	1.3	1.5		Tj=25°C	
		-	1.5	-		Tj=175°C	
					μA	Vr=650V	
Reverse Current	IR	-	-	50		Tj=25°C	
		-	-	200		Tj=175°C	
					nC	V ≈=400V,Tj=25° ℃	
Total Capacitive Charge	Qc	-	27	-		$Q_{C} = \int_{0}^{V_{R}} C(V) dV$	
					pF	Tj =25 ℃, f=1MHz	
Total Capacitance	С	-	561	-		Vr=0V	
		-	55	-		VR=200V	
		-	43	-		V _R =400V	

Electrical Characteristic (at Tj = 25 °C, unless otherwise specified)

Characteristics Curve:





0

25

50

75

100

т_с (°С)

125

175

150



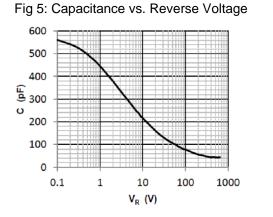


Fig 6: Reverse Charge vs. Reverse Voltage

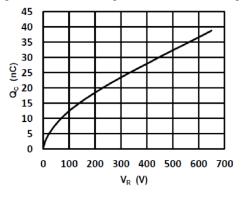


Fig 7: Typical Capacitance Stored Energy

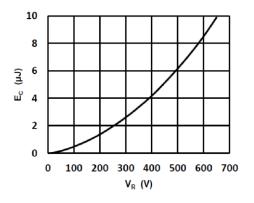
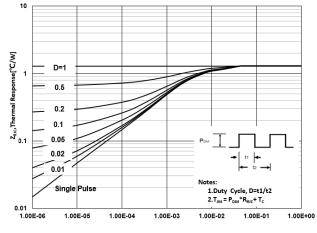


Fig 8: Transient Thermal Impandance

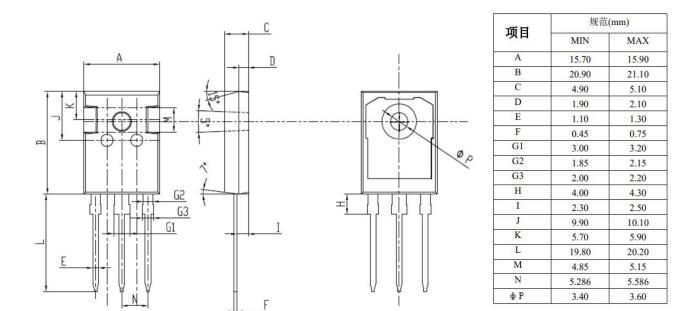


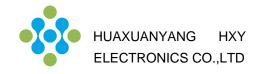
T , Rectangular Pulse Duration [sec]



Package Dimensions

Package TO-247





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